NSN 5962-01-234-0879

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N/a



View Online at https://aerobasegroup.com/nsn/5962-01-234-0879

Body Length:
0.380 inches
Body Width:
Between 0.340 inches and 0.380 inches
Body Height:
0.085 inches
Maximum Power Dissipation Rating:
794.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Om-51a/fr
Features Provided:
Hermetically sealed and burn in and programmable and schottky and 3-state output and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Prom
Precious Material And Location:
Terminal surface option gold
Precious Material:
Gold
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 flat leads
Shelf Life:

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Demilitarization:

Yes - demil/mli

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